

N0436N

N-channel MOSFET

40 V, 56 A, 4.7 mΩ

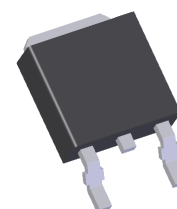
R07DS1414EJ0100

Rev.1.00

2019.9.30

Features

- Low on-state resistance :
 $R_{DS(on)} = 4.7 \text{ m}\Omega \text{ max. (} V_{GS} = 10 \text{ V, } I_D = 28 \text{ A)}$
- Low Ciss : $C_{iss} = 3200 \text{ pF typ. (} V_{DS} = 25 \text{ V)}$
- High current : $I_{D(DC)} = \pm 56 \text{ A}$
- RoHS Compliant
- Quality Grade : Standard
- Applications: For high current switching



TO-252

Ordering Information

Orderable Part Number	Package	Packing
N0436N-ZK-E1-AY	TO-252, Pb-free ^{Note1}	3000 pcs / Tape and Reel

Note: 1. Pb-free means that this product does not contain lead in the external electrode.

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	40	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	± 20	V
Drain Current (DC) ($T_C = 25^\circ\text{C}$)	$I_{D(DC)}$	± 56	A
Drain Current (pulse) ^{Note2}	$I_{D(pulse)}$	± 112	A
Total Power Dissipation ($T_C = 25^\circ\text{C}$)	P_{T1}	87.4	W
Total Power Dissipation ($T_A = 25^\circ\text{C}$)	P_{T2}	1.0	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to 150	$^\circ\text{C}$
Single Avalanche Current ^{Note3}	I_{AS}	34	A
Single Avalanche Energy ^{Note3}	E_{AS}	113	mJ

Note : Continuous heavy condition (e.g. high temperature/voltage/current or high variation of temperature) may affect a reliability even if it is within the absolute maximum ratings. Please consider derating condition for appropriate reliability in reference Renesas Semiconductor Reliability Handbook (Recommendation for Handling and Usage of Semiconductor Devices) and individual reliability data.

Notes: 2. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

3. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = 20 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$, $L = 100 \mu\text{H}$

Thermal Resistance

Item	Symbol	Max. Value ^{Note4}	Unit
Channel to Case Thermal Resistance	$R_{th(ch-C)}$	1.43	$^\circ\text{C/W}$
Channel to Ambient Thermal Resistance	$R_{th(ch-A)}$	125	$^\circ\text{C/W}$

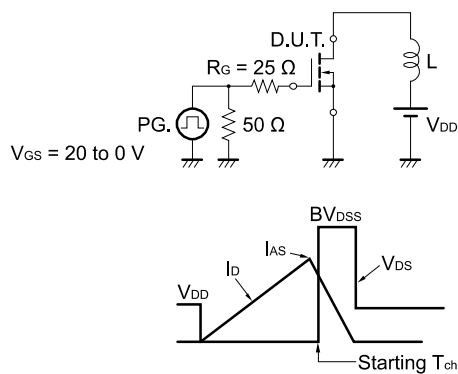
Notes: 4. This data is the designed target maximum value on Renesas's measurement condition. (Not tested)

Electrical Characteristics ($T_A = 25^\circ\text{C}$)

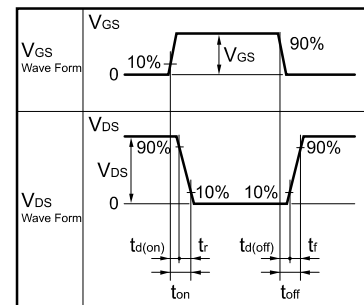
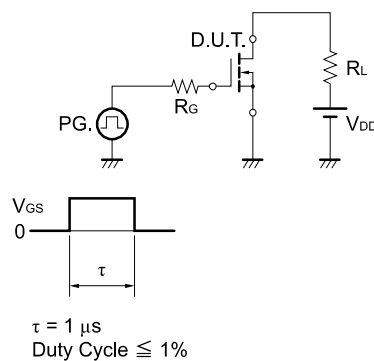
Item	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Zero Gate Voltage Drain Current	I_{DSS}			1	μA	$V_{DS} = 40\text{ V}$, $V_{GS} = 0\text{ V}$
Gate Leakage Current	I_{GSS}			± 100	nA	$V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0\text{ V}$
Gate to Source Cut-off Voltage	$V_{GS(off)}$	2.0		4.0	V	$V_{DS} = 10\text{ V}$, $I_D = 1\text{ mA}$
Forward Transfer Admittance ^{Note5}	$ y_{fs} $		49		S	$V_{DS} = 5\text{ V}$, $I_D = 28\text{ A}$
Drain to Source On-state Resistance ^{Note5}	$R_{DS(on)}$		3.9	4.7	m Ω	$V_{GS} = 10\text{ V}$, $I_D = 28\text{ A}$
Input Capacitance	C_{iss}		3200		pF	$V_{DS} = 25\text{ V}$
Output Capacitance	C_{oss}		325		pF	$V_{GS} = 0\text{ V}$
Reverse Transfer Capacitance	C_{rss}		195		pF	$f = 1\text{ MHz}$
Turn-on Delay Time	$t_{d(on)}$		23		ns	$V_{DD} = 20\text{ V}$, $I_D = 28\text{ A}$
Rise Time	t_r		12		ns	$V_{GS} = 10\text{ V}$
Turn-off Delay Time	$t_{d(off)}$		51		ns	$R_G = 0\ \Omega$
Fall Time	t_f		10		ns	
Total Gate Charge	Q_G		62		nC	$V_{DD} = 32\text{ V}$
Gate to Source Charge	Q_{GS}		16		nC	$V_{GS} = 10\text{ V}$
Gate to Drain Charge	Q_{GD}		20		nC	$I_D = 56\text{ A}$
Body Diode Forward Voltage ^{Note5}	$V_{F(S-D)}$			1.5	V	$I_F = 56\text{ A}$, $V_{GS} = 0\text{ V}$
Reverse Recovery Time	t_{rr}		30		ns	$I_F = 56\text{ A}$, $V_{GS} = 0\text{ V}$
Reverse Recovery Charge	Q_{rr}		15		nC	$di/dt = 100\text{ A}/\mu\text{s}$

Notes: 5. Pulsed test

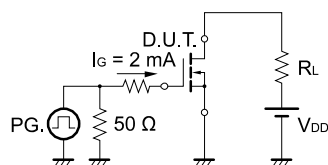
TEST CIRCUIT 1 AVALANCHE CAPABILITY

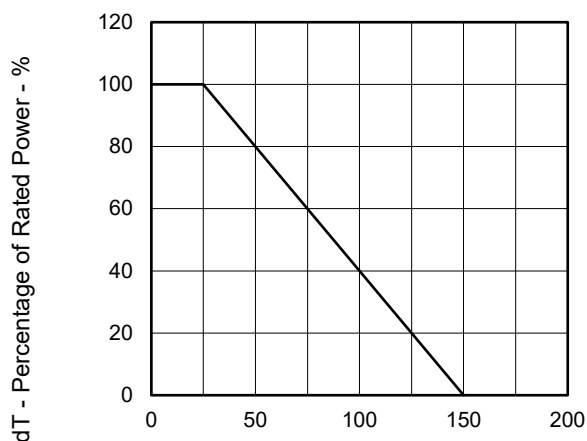
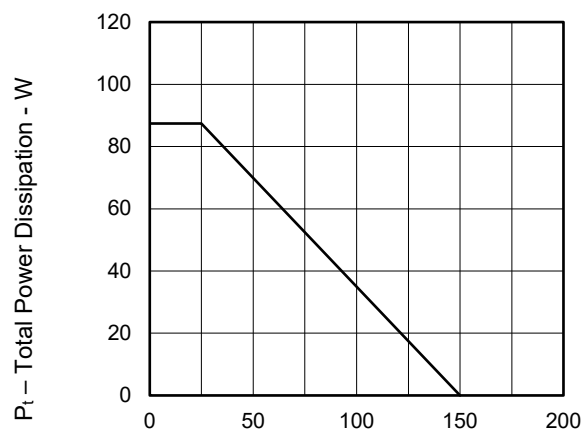


TEST CIRCUIT 2 SWITCHING TIME

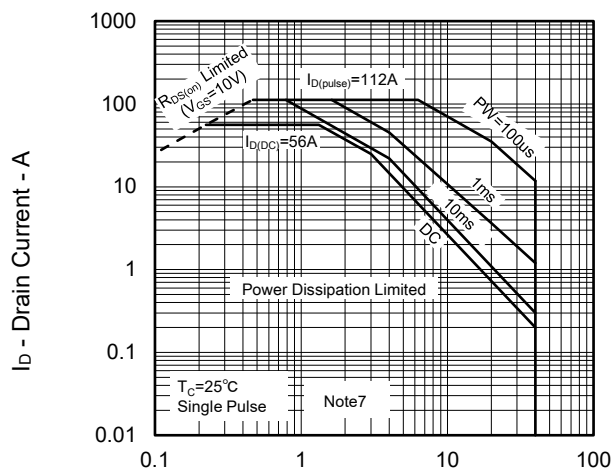


TEST CIRCUIT 3 GATE CHARGE

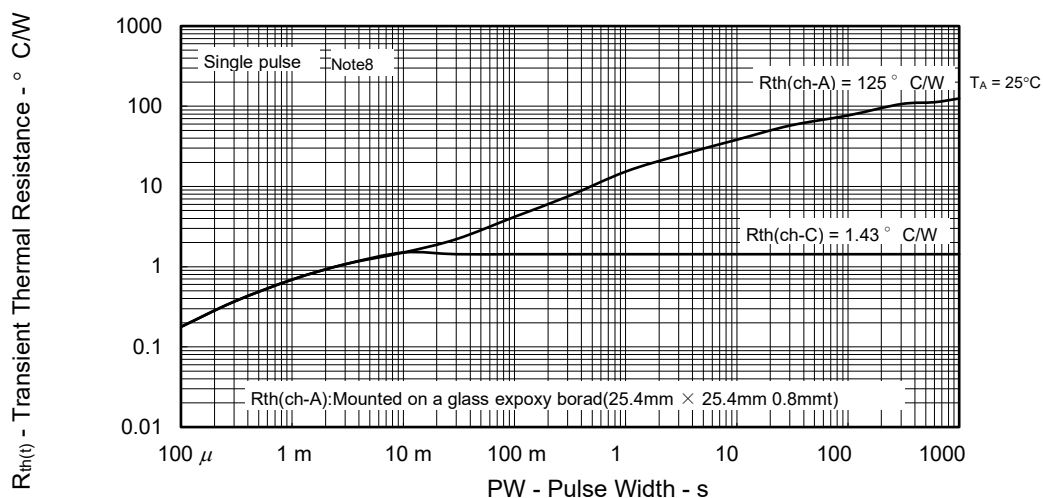


Typical Characteristics Note6DERATING FACTOR OF FORWARD BIAS
SAFE OPERATING AREAT_C - Case Temperature - °CTOTAL POWER DISSIPATION vs.
CASE TEMPERATURET_C - Case Temperature - °C

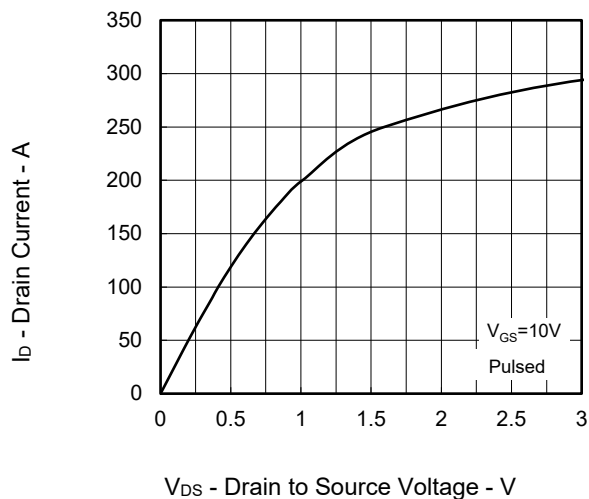
FORWARD BIAS SAFE OPERATING AREA

V_{DS} - Drain to Source Voltage - V

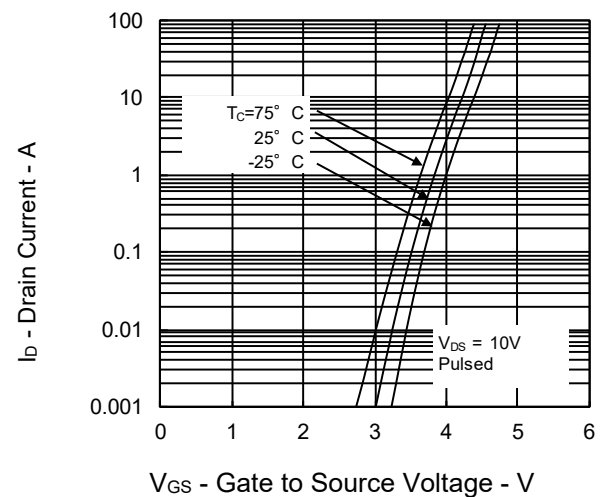
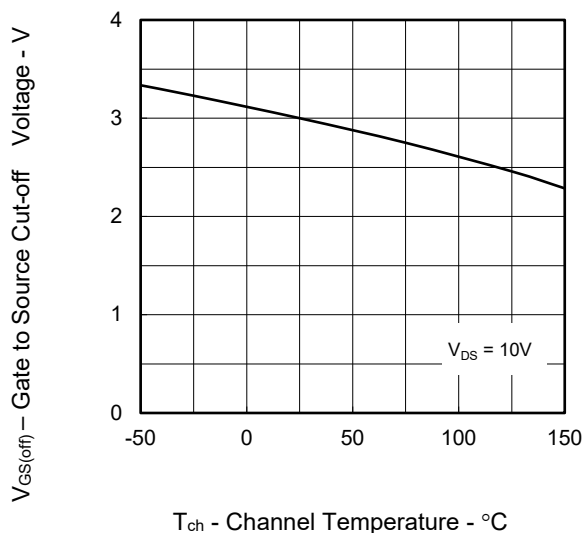
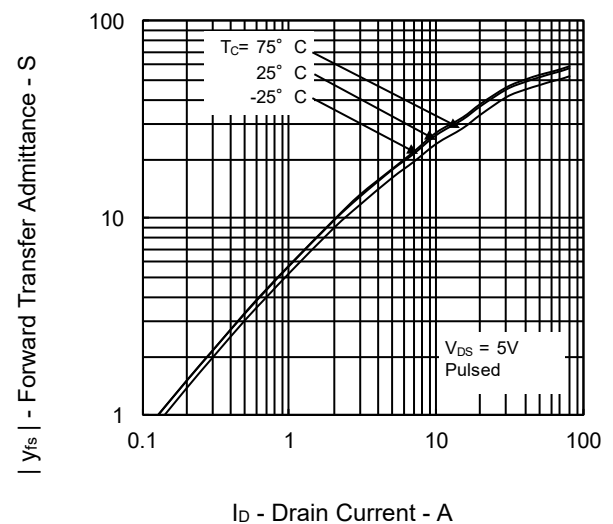
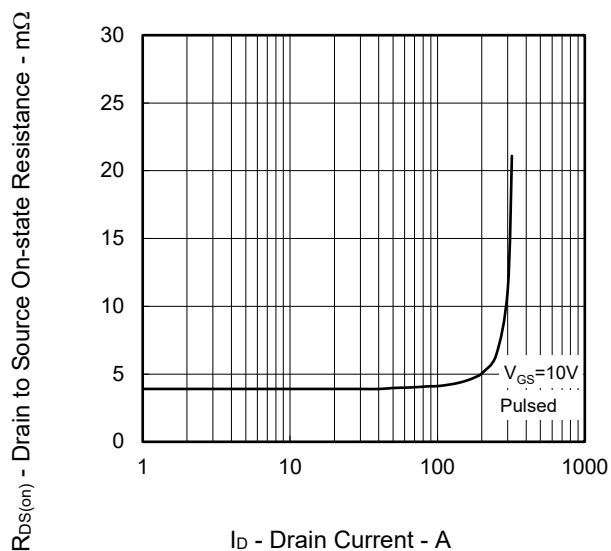
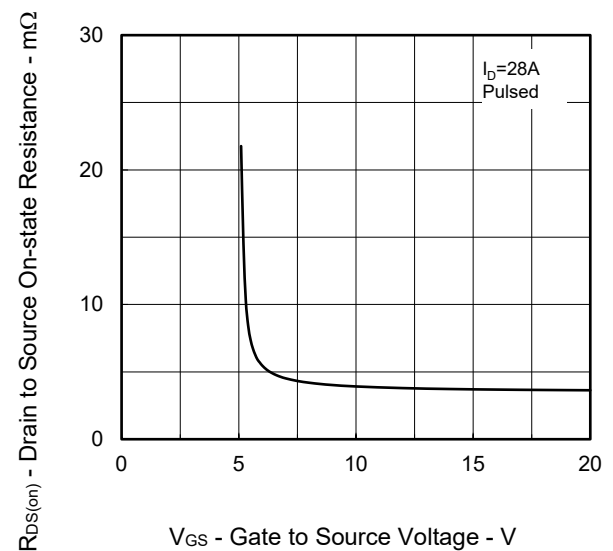
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

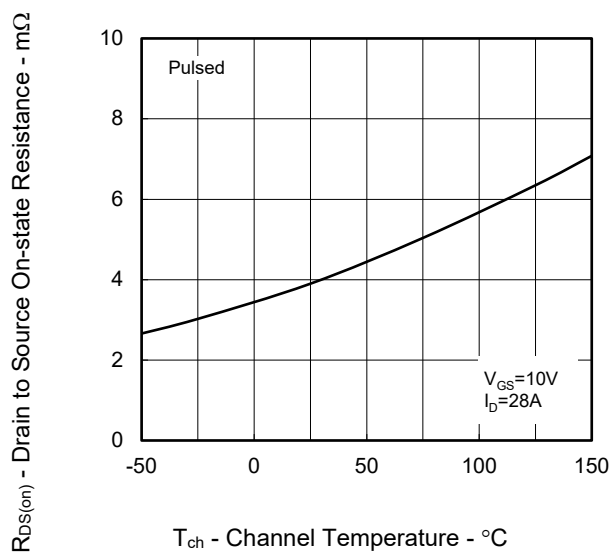
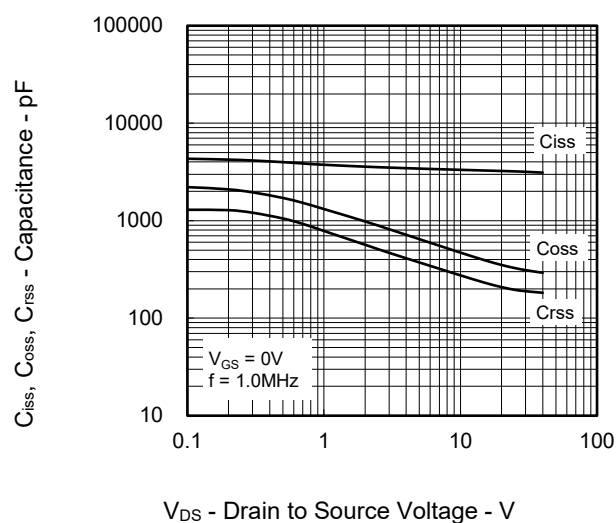


- Notes: 6. Designed target value on Renesas measurement condition. (T_C = 25°C, unless otherwise specified)
7. This data is the designed value on Renesas's measurement condition. Renesas recommends that operating conditions are designed according to a document "Power MOSFET/IGBT Attention of Handling Semiconductor Devices (R07ZZ0010)".
8. This data is the designed target maximum value on Renesas's measurement condition.

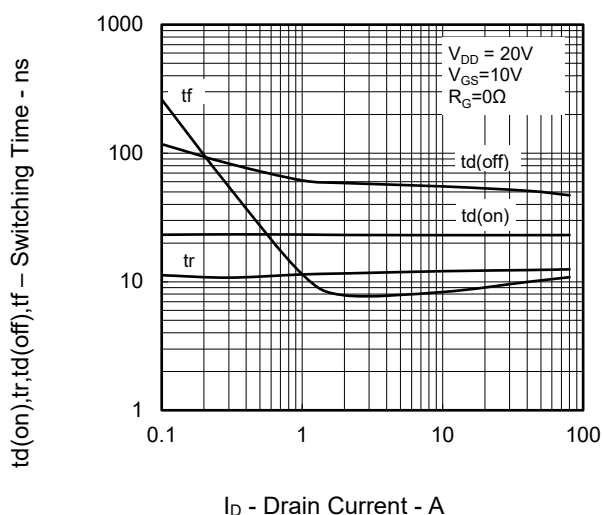
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE

FORWARD TRANSFER CHARACTERISTICS

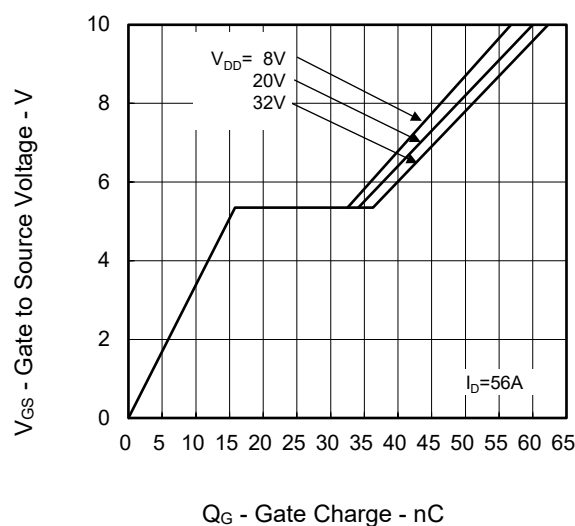
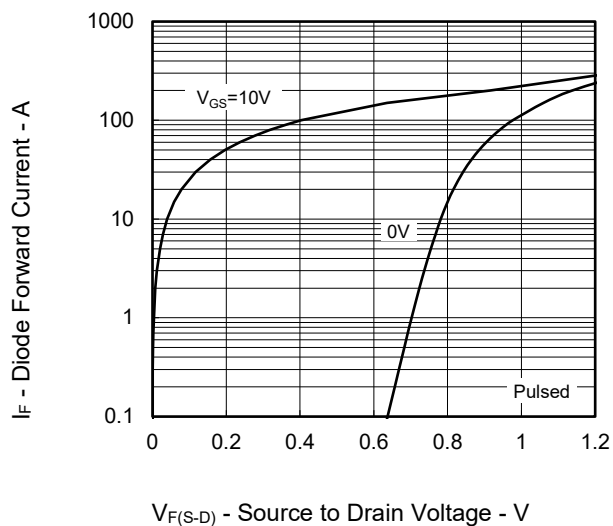
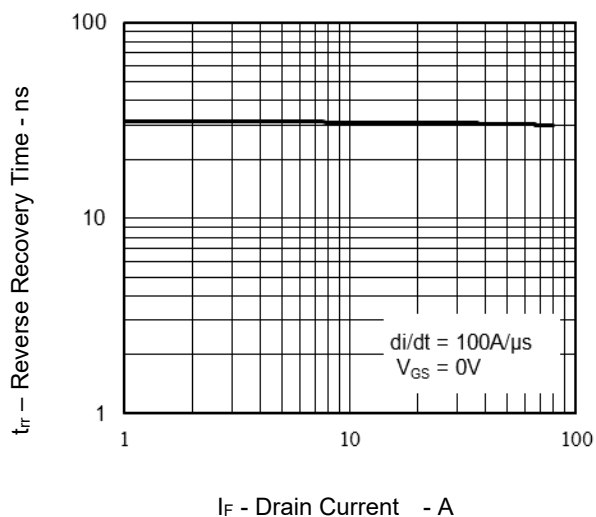
GATE TO SOURCE THRESHOLD VOLTAGE
vs. CHANNEL TEMPERATUREFORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENTDRAIN TO SOURCE ON-STATE
RESISTANCE vs. DRAIN CURRENTDRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE

DRAIN TO SOURCE ON-STATE
RESISTANCE vs. CHANNEL TEMPERATURECAPACITANCE vs. DRAIN TO SOURCE
VOLTAGE

SWITCHING CHARACTERISTICS



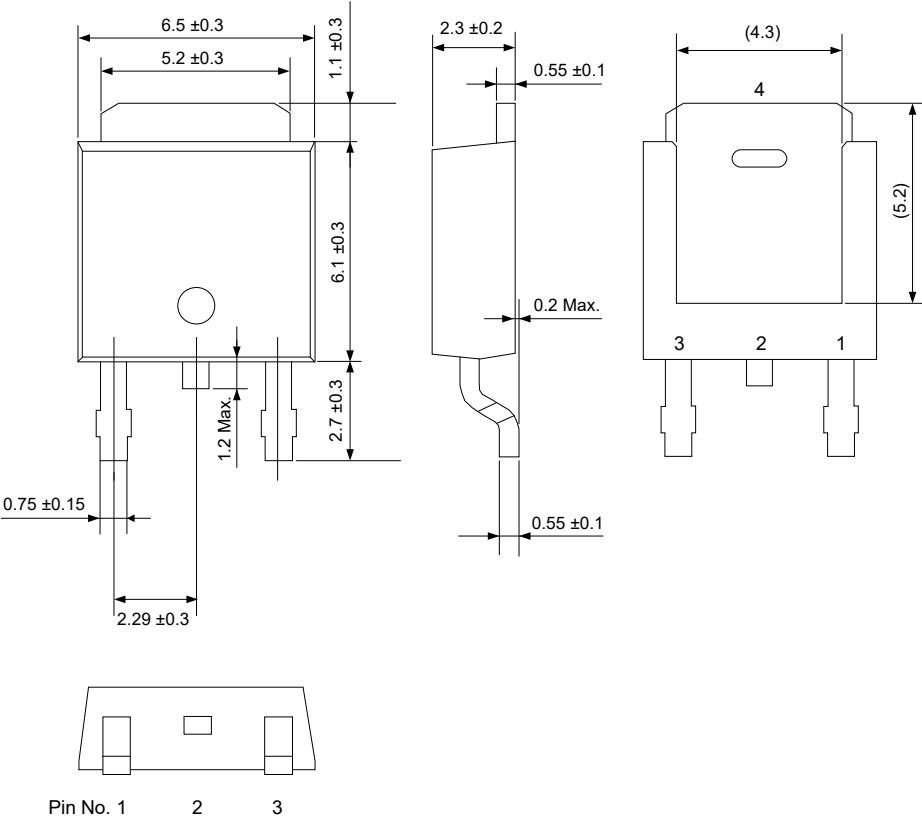
DYNAMIC INPUT CHARACTERISTICS

SOURCE TO DRAIN DIODE FORWARD
VOLTAGEREVERSE RECOVERY TIME vs.
DRAIN CURRENT

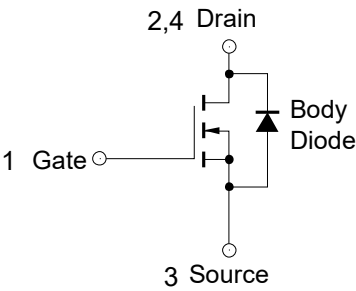
Package Drawings (Unit: mm)

Package Name	JEITA Package Code	JEDEC Code	RENESAS Code	Previous Code	MASS (Typ) [g]
TO-252	—	TO-252	PRSS0004ZK-A	TO-252A	0.32

Unit: mm



Equivalent Circuit



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